

MJ15022 (NPN), MJ15024 (NPN)

Silicon Power Transistors

The MJ15022 and MJ15024 are power transistors designed for high power audio, disk head positioners and other linear applications.

Features

- High Safe Operating Area
- High DC Current Gain
- These Devices are Pb-Free and are RoHS Compliant*
- Complementary to MJ15023 (PNP), MJ15025 (PNP)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	200 250	Vdc
Collector-Base Voltage	V_{CBO}	350 400	Vdc
Emitter-Base Voltage	V_{EBO}	5	Vdc
Collector-Emitter Voltage	V_{CEX}	400	Vdc
Collector Current – Continuous	I_C	16	A dc
Collector Current – Peak (Note 1)	I_{CM}	30	A dc
Base Current – Continuous	I_B	5	A dc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	250 1.43	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle \leq 10%.

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.70	$^\circ\text{C/W}$

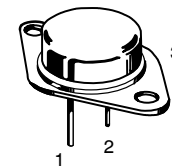
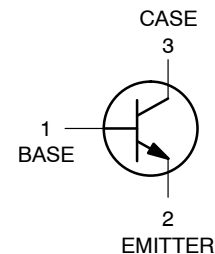


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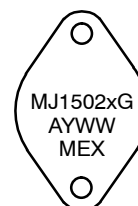
**16 AMPERES
SILICON POWER TRANSISTORS
200 – 250 VOLTS, 250 WATTS**

SCHEMATIC



**TO-204AA (TO-3)
CASE 1-07
STYLE 1**

MARKING DIAGRAM



MJ1502x = Device Code
x = 2 or 4
G = Pb-Free Package
A = Assembly Location
Y = Year
WW = Work Week
MEX = Country of Origin

ORDERING INFORMATION

Device	Package	Shipping
MJ15022G	TO-204 (Pb-Free)	100 Units / Tray
MJ15024G	TO-204 (Pb-Free)	100 Units / Tray

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 2) ($I_C = 100\text{ mAdc}$, $I_B = 0$)	MJ15022 MJ15024	$V_{CEO(sus)}$	200 250	-
Collector Cutoff Current ($V_{CE} = 200\text{ Vdc}$, $V_{BE(off)} = 1.5\text{ Vdc}$) ($V_{CE} = 250\text{ Vdc}$, $V_{BE(off)} = 1.5\text{ Vdc}$)	MJ15022 MJ15024	I_{CEX}	- -	250 250
Collector Cutoff Current ($V_{CE} = 150\text{ Vdc}$, $I_B = 0$) ($V_{CE} = 200\text{ vdc}$, $I_B = 0$)	MJ15022 MJ15024	I_{CEO}	- -	500 500
Emitter Cutoff Current ($V_{CE} = 5\text{ Vdc}$, $I_B = 0$)		I_{EBO}	-	500
SECOND BREAKDOWN				
Second Breakdown Collector Current with Base Forward Biased ($V_{CE} = 50\text{ Vdc}$, $t = 0.5\text{ s}$ (non-repetitive)) ($V_{CE} = 80\text{ Vdc}$, $t = 0.5\text{ s}$ (non-repetitive))		$I_{S/b}$	5 2	- -
ON CHARACTERISTICS				
DC Current Gain ($I_C = 8\text{ Adc}$, $V_{CE} = 4\text{ Vdc}$) ($I_C = 16\text{ Adc}$, $V_{CE} = 4\text{ Vdc}$)		h_{FE}	15 5	60 -
Collector-Emitter Saturation Voltage ($I_C = 8\text{ Adc}$, $I_B = 0.8\text{ Adc}$) ($I_C = 16\text{ Adc}$, $I_B = 3.2\text{ Adc}$)		$V_{CE(sat)}$	- -	1.4 4.0
Base-Emitter On Voltage ($I_C = 8\text{ Adc}$, $V_{CE} = 4\text{ Vdc}$)		$V_{BE(on)}$	-	2.2
DYNAMIC CHARACTERISTICS				
Current-Gain - Bandwidth Product ($I_C = 1\text{ Adc}$, $V_{CE} = 10\text{ Vdc}$, $f_{test} = 1\text{ MHz}$)		f_T	4	-
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f_{test} = 1\text{ MHz}$)		C_{ob}	-	500

2. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2\%$.

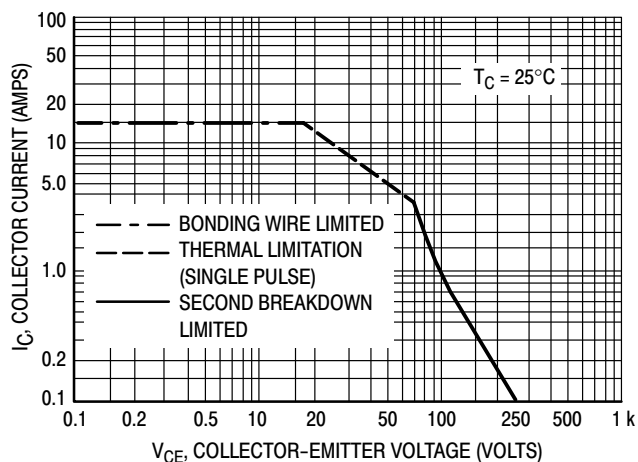


Figure 1. Active-Region Safe Operating Area

There are two limitations on the powerhandling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 1 is based on $T_{J(pk)} = 200^\circ\text{C}$; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values I_{on} than the limitations imposed by second breakdown.

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TYPICAL CHARACTERISTICS

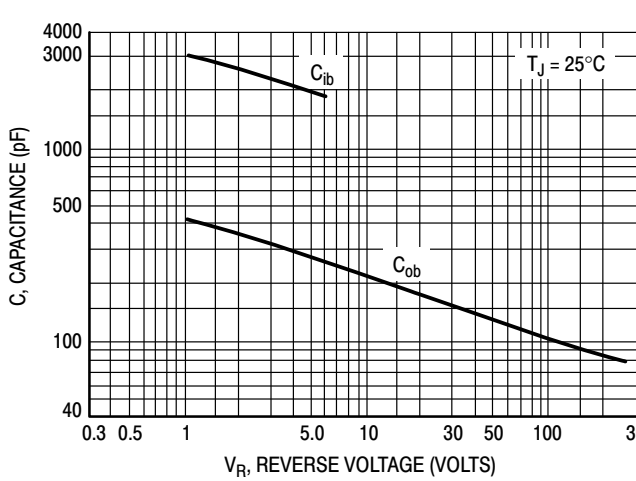


Figure 2. Capacitances

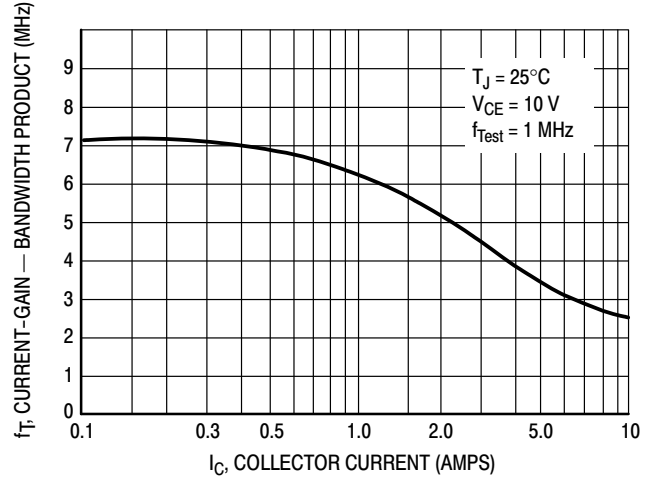


Figure 3. Current-Gain — Bandwidth Product

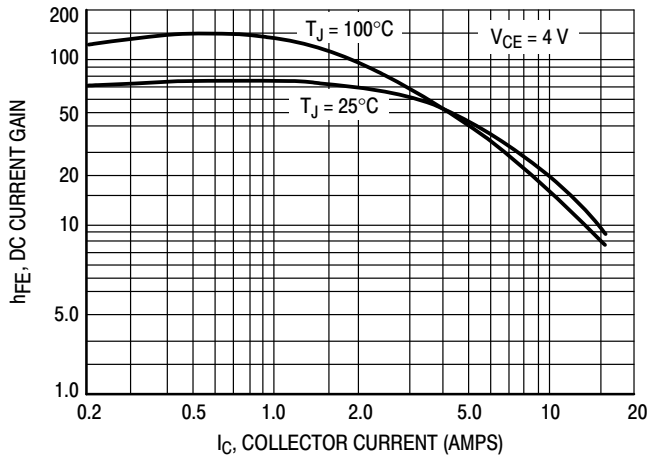


Figure 4. DC Current Gain

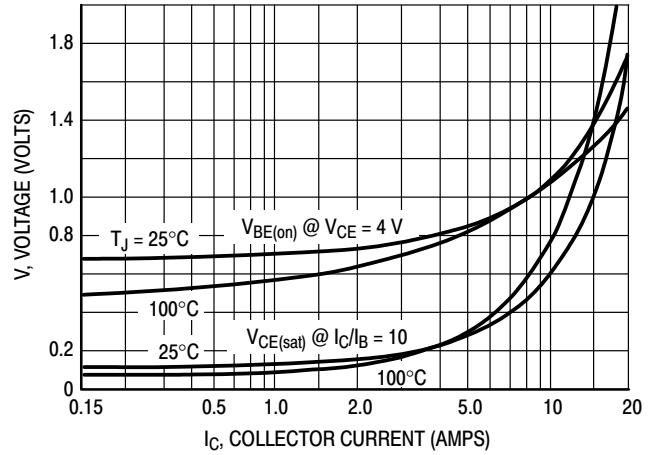


Figure 5. "On" Voltage

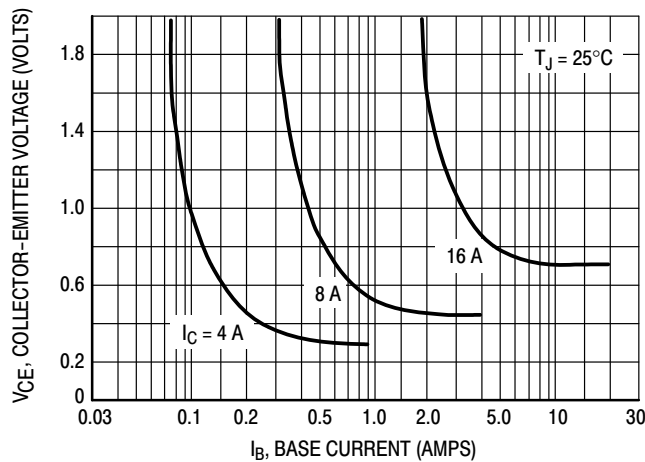


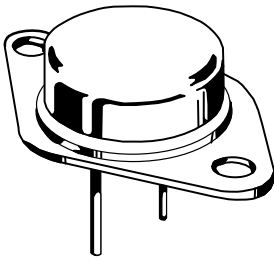
Figure 6. Collector Saturation Region

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

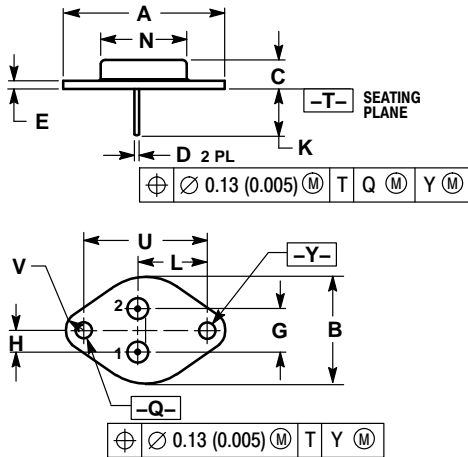


TO-204 (TO-3) CASE 1-07 ISSUE Z

DATE 05/18/1988



SCALE 1:1



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF	---	39.37 REF	---
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC	---	10.92 BSC	---
H	0.215 BSC	---	5.46 BSC	---
K	0.440	0.480	11.18	12.19
L	---	0.665 BSC	---	16.89 BSC
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC	---	30.15 BSC	---
V	0.131	0.188	3.33	4.77

- | | | | | |
|--|--|---|---|---|
| <p>STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR</p> | <p>STYLE 2:
PIN 1. BASE
2. COLLECTOR
CASE: EMITTER</p> | <p>STYLE 3:
PIN 1. GATE
2. SOURCE
CASE: DRAIN</p> | <p>STYLE 4:
PIN 1. GROUND
2. INPUT
CASE: OUTPUT</p> | <p>STYLE 5:
PIN 1. CATHODE
2. EXTERNAL TRIP/DELAY
CASE: ANODE</p> |
| <p>STYLE 6:
PIN 1. GATE
2. EMITTER
CASE: COLLECTOR</p> | <p>STYLE 7:
PIN 1. ANODE
2. OPEN
CASE: CATHODE</p> | <p>STYLE 8:
PIN 1. CATHODE #1
2. CATHODE #2
CASE: ANODE</p> | <p>STYLE 9:
PIN 1. ANODE #1
2. ANODE #2
CASE: CATHODE</p> | |

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